# MM3724 series

#### 概要 / OUTLINE

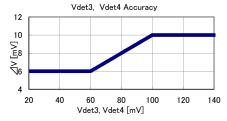
MM3724シリーズは高耐圧CMOSプロセスによるLiイオン/Liポリマー2次電池の過充電、過放電および過電流保護用ICです。Liイオン/Liポリマー電池1セルの過充電、過放電、放電過電流、充電過電流及び短絡の検出が可能です。内部は電圧検出器、短絡検出回路、基準電圧源、発振回路、カウンタ回路、論理回路等から構成されています。

The MM3724 series are protection IC using high voltage CMOS process for overcharge, overdischarge and overcurrent protection of the rechargeable Lithium-ion or Lithium-polymer battery. The overcharge, overdischarge, discharging overcurrent, charging overcurrent, and short protection of the rechargeable one-cell Lithium-ion or Lithium-polymer battery can be detected. Each of these IC composed of four voltage detectors, short detection circuit, reference voltage sources, oscillator, counter circuit and logical circuits.

#### 特徽 / FEATURES

1, 検出電圧選択範囲と精度 / Range and accuracy of c	letection voltage		(特記なき場合、Ta=+25℃)
項目/Item	記号/SYMBOL	設定範囲/Range	精度/Accuracy
・過充電検出電圧	Vdet1	3.6V to 5.0V	±20mV
Overcharge detection voltage		5mV step	$\pm 25$ mV (Ta=-20 to $+60$ °C)
・過充電復帰電圧	Vrel1	Vdet1-0.2V to Vdet1	±30mV
Overcharge release voltage		5mV step	
・過放電検出電圧	Vdet2	2.0V to 3.0V	±35mV
Overdischarge detection voltage		50mV step	
・過放電復帰電圧	Vrel2	2.0V to 3.0V	+65 / -35mV (In case Vdet2=Vrel2)
Overdischarge release voltage		50mV step	+90 / -65mV (In case Vdet2≠Vrel2)
・放電過電流検出電圧	Vdet3	20mV to 300mV	±⊿V *1
Discharging overcurrent detection voltage		1mV step	
<ul><li>・充電過電流検出電圧</li></ul>	Vdet4	-20mV to -300mV	±⊿V *1
Charging overcurrent detection voltage		1mV step	
· 短絡検出電圧	Vshort	40mV to 350mV	±8%
Short detection voltage		1mV step	
・0V充電禁止電池電圧	Vst	1.3V to 1.8V / 0.1V step	±100mV
0V battery charge inhibition battery voltage		0.9V	±300mV

#### \*1 過電流検出精度 / Current detection voltage Accuracy



#### 2, 遅延時間の設定 / Delay time setting

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• 過充電検出遅延時間	tVdet1	256ms to 4.6s
Overcharge detection delay time		
<ul><li>過放電検出遅延時間</li></ul>	tVdet2	8ms to 256ms
Overdischarge detection delay time		
<ul><li>放電過電流検出遅延時間</li></ul>	tVdet3	8ms to 256ms
Discharging overcurrent detection delay tim	ne	
<ul><li>充電過電流検出遅延時間</li></ul>	tVdet4	6ms to 64ms
Charging overcurrent detection delay time		
• 短絡検出遅延時間	tVshort	250us to 400us
Short detection delay time		

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#### 3, 消費電流 / Current consumption

・通常動作モード時 / Normal mode Typ. 3.0uA, Max. 6.0uA
・スタンバイモード時 / Stand-by mode Max. 0.1uA (過放電ラッチ機能ありの場合 / In case Overdischarge latch function Enable.)
Max 0.6uA (過放電ラッチ機能なしの場合 / In case Overdischarge latch function Disable.)

# 4, 0V電池への充電機能 / 0V battery Charge function

"許可"/"禁止"選択可能 Selectable "Permission" or "inhibition"

設定節囲/Range

## 5, 絶対最大定格 / Absolute maximum ratings

・VDD端子 / VDD pin VSS-0.3V to 12V
・COUT端子、V-端子 / COUT pin and V- pin VDD-28V to VDD+0.3V
・DOUT端子 / DOUT pin VSS-0.3V to VDD+0.3V
・保存温度 / Storage temperature -55 to +125°C
・動作周囲温度 / Operation temperature -40 to +85°C

#### 6, パッケージラインナップ/ PKG Line up

SSON-6J SON-6C

# \* 各ランクの詳細は製品ラインナップを参照ください。

Please refer to the "PRODUCT LINE UP" for details of each rank. 上記以外の仕様をご希望の場合は、弊社までお問い合わせください Please inquire to us, if you need another spec.

# 電気的特性 / ELECTRICAL CHARACTERISTICS

特記なき場合 Ta=25℃ / Ta=25℃, unless otherwise specified

項目/Item	単位/Unit	記号/Symbol		Min	Typ	therwise specified Max
動作電圧	V			1.5		
Operating voltage	V	Vop		1.5	-	5.5
動作周囲温度	°C	Ta		-40	_	85
Operating Ambient temperature	C	Id		-40	_	03
過電流復帰抵抗	kohms	Rshort	VDD=3.6V, CS=0V, V-=2.0V	Rshort*0.6	Rshort	Rshort*2.0
Discharge overcurrent release resistance	KUIIIIS	KSHOLL	VDD=3.0V, C3=0V, V==2.0V	KSHOIT 0.0	KSHOIT	KSHOIT 2.0
V-端子プルアップ抵抗	kohms	Rpu	VDD=2.0V, CS=V-=0V	Rpu*0.5	Rpu	Rpu*2.0
V- terminal pull-up resistances	KOIIIIS	Кри	VDD=2.0V, C3=V-=0V	кри 0.5	Кри	Кри 2.0
COUT Lレベル出力電圧	V	VcoL	Icout=30uA, VDD=4.5V	_	0.1	0.5
COUT L level output voltage		7002	10000 0000 4 122 1101		0.1	0.5
COUT Hレベル出力電圧	V	VcoH	Icout=-30uA, VDD=4.0V	VDD-0.5	VDD-0.1	_
COUT H level output voltage				1 = 2 = 0.0		
DOUT Lレベル出力電圧	V	VdoL	Idout=30uA, VDD=2.0V	-	0.1	0.5
DOUT L level output voltage						
DOUT Hレベル出力電圧	V	VdoH	Idout=-30uA, VDD=4.0V	VDD-0.5	VDD-0.1	-
DOUT H level output voltage			·			
消費電流 Current consumption	uA	Idd	VDD=4.0V, V-=CS=0V	-	3.0	6.0
•			VDD 2.0V 00.0V			
スタンバイ電流			VDD=2.0V, CS=0V *3	-	-	0.1
Current consumption at stand-by	uA	Is				
			VDD=2.0V, CS=0V	-	0.3	0.6
0V充電許可充電器電圧			Vst=VDD-V-, VDD=CS=0V			
0V 尤电許可尤电器电压 0V battery charge permission charger voltage	V		*1	-	-	1.2
0V充電禁止電池電圧		Vst	Vst=VDD-VSS, V-=CS=0V			
0V D 电亲正电池电压 0V battery charge inhibition battery voltage	V		*2	Vst-0.1	Vst	Vst+0.1
過充電検出電圧			Ta=25°C V-=CS=0V	Vdet1-0.020		Vde1+0.020
Overcharge detection voltage	V	Vdet1	Ta=-20 to 60°C V-=CS=0V	Vdet1-0.025	Vdet1	Vde1+0.025
過充電復帰電圧		_				
Overcharge release voltage	V	Vrel1	*5	Vrel1-0.030	Vrel1	Vrel1+0.030
過放電検出電圧	.,					
Overdischarge detection voltage	V	Vdet2	V-=CS=0V	Vdet1-0.035	Vdet2	Vde1+0.035
過放電復帰電圧			In case Vdet2=Vrel2 *3 *5	Vrel2-0.035		Vrel2+0.065
Overdischarge release voltage	V	Vrel2	In case vdetz=vreiz **3 **5	Vreiz-0.035 Vrei2		Vrei2+0.065
	V	vreiz	In case Vdet2≠Vrel2 *4 *5	Vdet1-0.065	vreiz	Vdet1+0.090
			III case vuetz + vietz + + 5	vuet1-0.003		Vue:1+0.090
放電過電流検出電圧	V	Vdet3	VDD=3.6V, V-=0V *6	Vdet3-⊿V	Vdet3-1	Vdet3+⊿V
Discharging overcurrent detection voltage	V	vuets	VDD=3.0V, V=0V 0	vuet5-⊠v	vuet5-1	Vuet5+∠]V
充電過電流検出電圧	V	Vdet4	VDD=3.6V, V-=0V *6	Vdet4-⊿V	Vdet4	Vdet4+⊿V
Charging overcurrent detection voltage	,		5.5., . 00			
短絡検出電圧	V	Vshort	VDD=3.6V, CS=VSS	Vshort*0.92	Vshort	Vshort*1.08
Short detection voltage			,			22.2
過充電検出遅延時間	ms	tVdet1		tVdet1*0.8	tVdet1	tVdet1*1.2
Overcharge detection delay time						
過放電検出遅延時間	ms	tVdet2		tVdet2*0.8	tVdet2	tVdet2*1.2
Overdischarge detection delay time						
放電過電流検出遅延時間	ms	tVdet3		tVdet3*0.8	tVdet3	tVdet3*1.2
Discharging overcurrent detection delay time 充電過電流検出遅延時間						
	ms	tVdet4		tVdet4*0.8	tVdet4	tVdet4*1.2
Charging overcurrent detection delay time 短絡検出遅延時間						
	us	tVshort		tVshort*0.8	tVshort	tVshort*1.2
Short detection delay time	I	l			l	

<sup>\*1 0</sup>V電池への充電機能"許可"の場合/In case 0V battery charge function "Permission". \*2 0V電池への充電機能"禁止"の場合/In case 0V battery charge function "inhibition".

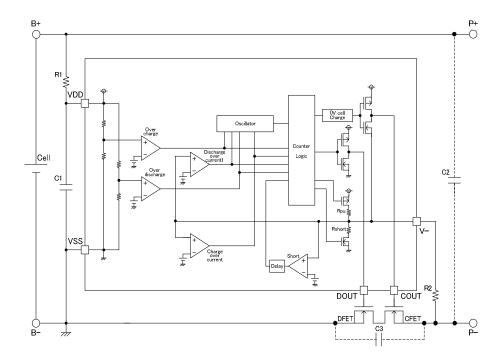
<sup>\*3</sup> 過放電ラッチ機能"あり"の場合/Overdischarge mode latch function "Enable".

<sup>\*4</sup> 過放電ラッチ機能"なし"の場合/Overdischarge mode latch function "Disable".

<sup>\*5</sup> 復帰条件は各ランクの仕様書を参照ください./Please refer to each specifications for release condition.

<sup>\*6</sup> 過電流検出精度/Current detection voltage Accuracy

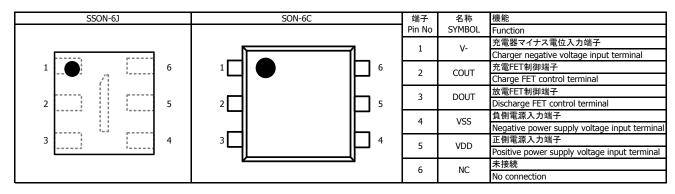
# 応用回路例 / Typical application circuit



記号	品部	最小値		最大値	目的
Symbol	Part	Min.	Typ.	Max.	Purpose
R1	Resistor	-	100Ω	1.0kΩ	電源電圧変動対策、ESD対策 For voltage fluctuation, For ESD
C1	Capacitor	0.01uF	0.1uF	1.0uF	電源電圧変動対策 For voltage fluctuation
R2	Resistor	-	1.0kΩ	1.0kΩ	充電器逆接電流制限 Current limit for charger reverse connection
C2	Capacitor	-	0.1uF	-	ノイズ対策 For exogenous noise
СЗ	Capacitor	-	0.1uF	-	ノイズ対策 For exogenous noise
DFET CFET	Nch MOS FET	-	-	-	充放電制御 Charge and discharge control

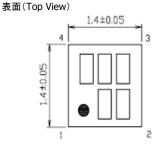
<sup>\*</sup> 本回路例および定数は、動作を保証するものではありません。実際のアプリケーションで十分な評価を実施の上、定数を設定してください。
This typical application circuit and constant value do not guarantee proper operation. Please evaluate thoroughly by actual application to set up constants.

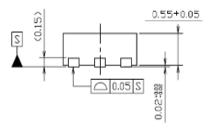
#### パッケージ、ピン配置 / PKG, Pin configuration

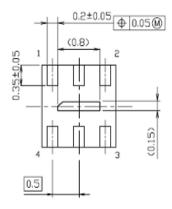


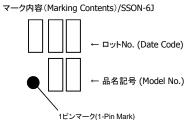
## パッケージ外形図 / PACKAGE DIMENSIONS

SSON-6J



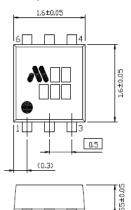


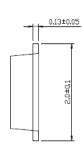


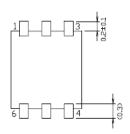




SON-6C 表面(Top View)

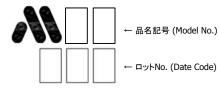






0,22±0,05 0,22±0,05 0,100

マーク内容(Marking Contents)/S0N-6C



# 製品ラインナップ / LINE UP

	ge			保護状態ラッチファンクション Protection mode latch function		ヒスキャンセル Hys-Cancel		太大機能 t release ction.	出電圧 detection ge			事压 eleas 事压 letec		電压release	検出電圧1 overcurrent voltage	流検出電圧 overcurrent on voltage	<b></b>   voltage	′ time *1	ent state				
機種名 MODEL	パッケージ PKG	トペッケー PKG 電 / 0V	_ im D	過放電 erdischarge t電過電流	唄ら	過充電 Overcharge	過放電 verdischarge	放電過電流復帰範囲拡大梯 Discharging overcurrent rele range extended function.	過充電検出電圧 Overcharge detect voltage	wordsyse 過充電復帰電圧 Overcharge relead	過放電検出 <sup>;</sup> Overdischarge c voltage	過放電復帰電圧 Overdischarge rele voltage	放電過電流検出 Discharging over detection volt	充電過電流検出電圧 Charging overcurren detection voltage	短絡検出電圧 Short detection vo	遅延時間/ Delay	状況/Developm						
			J	ò	放電 Discharge	Disch	J	5 6	Ó	Ó	0	0	0	一 Disch ra	Vdet1 [V]	Vrel1 [V]	Vdet2 [V]	Vrel2 [V]	Vdet3-1 [V]	Vdet4 [V]	Vshort [V]	-	開発
MM3724AC1RRE	SSON-6J	0.9	Disable	Disable	Disable	Enable	Enable	Yes(VDD-0.9V)	4.425	4.225	2.500	2.900	0.032	-0.020	0.150	Α	MP						
MM3724CF2RRE	SSON-6J	0.9	Disable	Enable	Disable	Enable	-	Yes(VDD-0.9V)	4.280	4.080	2.300	2.300	0.032	-0.020	0.150	Α	ES						
MM3724CF3RRE	SSON-6J	0.9	Disable	Enable	Disable	Enable	-	Yes(VDD-0.9V)	4.280	4.080	2.300	2.300	0.064	-0.020	0.150	Α	ES						
MM3724CL2RRE	SSON-6J	Permission	Disable	Enable	Disable	Enable	-	Yes(VDD-0.9V)	4.280	4.080	2.300	2.300	0.032	-0.020	0.150	Α	ES						
MM3724VK1RRE	SSON-6J	2.4	Disable	Enable	Disable	Enable	-	Disable	4.415	4.240	2.800	2.800	0.050	-	0.900	В	ES						

# \*1 遅延時間/Delay time

	tVdet1 [s]	tVrel1 [ms]	tVdet2 [ms]	tVrel2 [ms]	tVdet3 [ms]	tVrel3 [ms]	tVdet4 [ms]	tVrel4 [ms]	tshort [us]
Α	1.024	16.00	96.00	1.00	12.00	1.00	10.00	1.00	300
В	1.024	8.00	24.00	4.00	12.00	4.00	-	-	400

<sup>\*</sup> 上記以外の仕様をご希望の場合は、弊社までお問い合わせください Please inquire to us, if you need another spec.